

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L3	34	"105173"	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2005/12/19 09:22
L4	6	"105173".ap.	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2005/12/19 09:23
L5	2	"105173".ap. and cha	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2005/12/19 09:23
L6	811	(magnetoresistive adj random adj access adj memory or mram) and gate and source and drain and bit adj line and word	US-PGPUB; USPAT	OR	OFF	2005/12/19 09:26
L7	1	("20020140016").PN.	USOCR; DERWENT	OR	OFF	2005/12/19 09:26
L8	2	"2002076460"	DERWENT	OR	OFF	2005/12/19 09:26
L9	1612	magnetoresistive random access memory or mram and vertical	US-PGPUB; USPAT	ADJ	OFF	2005/12/19 09:26
L10	1207	(magnetoresistive adj random adj access adj memory or mram) and vertical	US-PGPUB; USPAT	OR	OFF	2005/12/19 09:26
L11	4292	((365/157,171,173) or (257/295, 421)).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/12/19 09:26
L12	811	(magnetoresistive adj random adj access adj memory or mram) and gate and source and drain and bit adj line and word	US-PGPUB; USPAT	OR	OFF	2005/12/19 09:26
L13	1	anti-ferroelectric and pinned near ferromagnetic	US-PGPUB; USPAT	OR	OFF	2005/12/19 09:26
L14	1	(US-20040175887-\$).did.	US-PGPUB	OR	OFF	2005/12/19 09:26
L15	7	(magnetoresistive adj random adj access adj memory or mram) and vertical adj field	US-PGPUB; USPAT	OR	OFF	2005/12/19 09:26
L16	189	perner-f\$.in. and memory	US-PGPUB; USPAT	OR	OFF	2005/12/19 09:26
L17	38	L16 and gate and source and drain and bit adj line and word	US-PGPUB; USPAT	OR	OFF	2005/12/19 09:26
L18	16	L16 and magnetic and vertical	US-PGPUB; USPAT	OR	OFF	2005/12/19 09:26

L19	3	"105173".ap. and @pd>"20010101"	US-PGPUB; USPAT	OR	OFF	2005/12/19 09:26
L20	4	(("6503795") or ("6649953") or ("6885578") or ("6855564")).PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/12/19 09:26
L21	189	perner-f\$.in. and memory	US-PGPUB; USPAT	OR	OFF	2005/12/19 09:26
L22	561	magnetoresistive random access memory or mram and vertical field	US-PGPUB; USPAT	ADJ	OFF	2005/12/19 09:26
L23	887	(magnetoresistive adj random adj access adj memory or mram) and gate and source and drain and bit and word	US-PGPUB; USPAT	OR	OFF	2005/12/19 09:26
L24	811	(magnetoresistive adj random adj access adj memory or mram) and gate and source and drain and bit adj line and word	US-PGPUB; USPAT	OR	OFF	2005/12/19 09:26
L25	768	anti-ferroelectric	US-PGPUB; USPAT	OR	OFF	2005/12/19 09:26
S30	303	S29 and @pd>"20040429"	US-PGPUB; USPAT	OR	OFF	2005/04/13 16:17